

SANYO Semiconductors DATA SHEET

CPH3235 — NPN Epitaxial Planar Silicon Transistor

DC / DC Converter Applications

Applications

· Relay drivers, lamp drivers, motor drivers, strobes.

Features

- · Adoption of MBIT processes.
- · Large current capacitance.
- · Low collector-to-emitter saturation voltage.
- · High-speed switching.
- Narrow hFE range.
- Ultrasmall package permitting applied sets to be small and slim (mounting height: 0.9mm).
- · High allowable power dissipation.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		40	V
Collector-to-Emitter Voltage	VCEO		30	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	Ic		3	Α
Collector Current (Pulse)	ICP		5	Α
Base Current	IΒ		600	mA
Collector Dissipation	PC	Mounted on a ceramic board (600mm ² X0.8m)	0.9	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector Cutoff Current	ICBO	V _{CB} =30V, I _E =0			0.1	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =4V, I _C =0			0.1	μΑ
DC Current Gain	hFE	VCE=2V, IC=500mA	250		400	
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =500mA		450		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		20		pF

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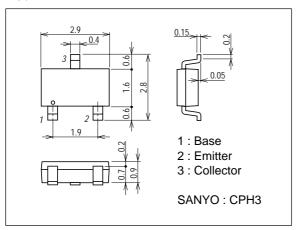
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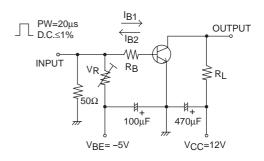
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector-to-Emitter Saturation Voltage	VCE(sat)1	IC=1.5A, IB=30mA		90	135	mV
	V _{CE} (sat)2	I _C =1.5A, I _B =75mA		75	115	mV
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	IC=1.5A, IB=30mA		0.83	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=10μA, IE=0	40			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =1mA, R _{BE} =∞	30			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=10μA, IC=0	5			V
Turn-ON Time	ton	See specified test circuit.		30		ns
Storage Time	tstg	See specified test circuit.		300		ns
Fall Time	tf	See specified test circuit.		15		ns

Package Dimensions

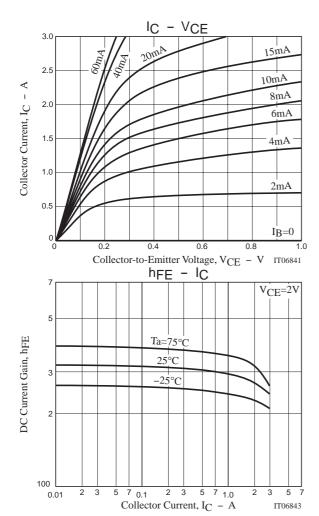
unit : mm 2150A

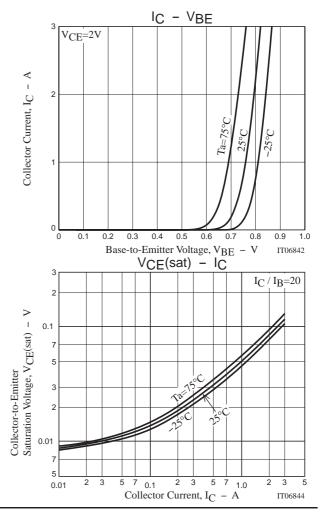


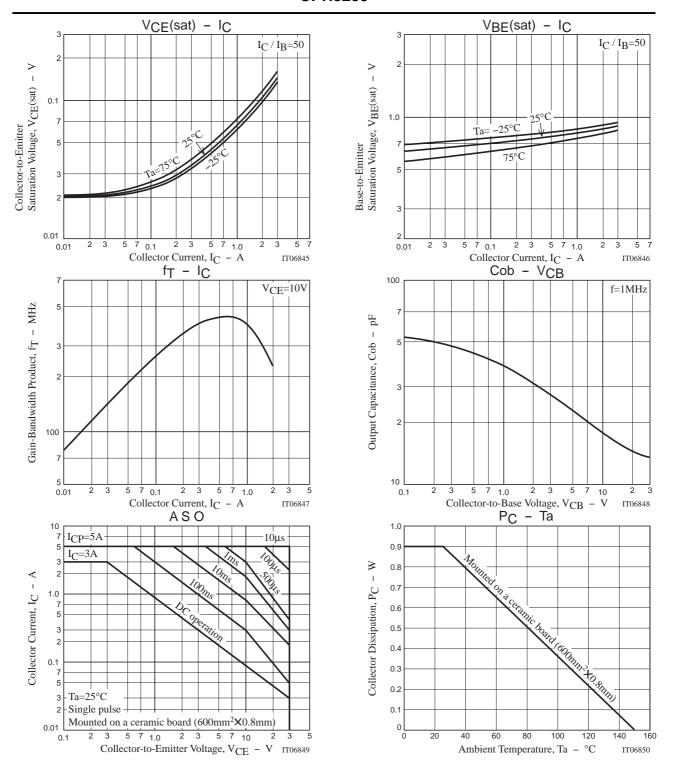
Switching Time Test Circuit



IC=20IB1= -20IB2=500mA







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